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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	10 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	32
Number of Macrocells	512
Number of Gates	10000
Number of I/O	172
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epm3512aqi208-10

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

...and More Features

- PCI compatible
- Bus-friendly architecture including programmable slew-rate control
- Open–drain output option
- Programmable macrocell flipflops with individual clear, preset, clock, and clock enable controls
- Programmable power–saving mode for a power reduction of over 50% in each macrocell
- Configurable expander product–term distribution, allowing up to 32 product terms per macrocell
- Programmable security bit for protection of proprietary designs
- Enhanced architectural features, including:
 - 6 or 10 pin– or logic–driven output enable signals
 - Two global clock signals with optional inversion
 - Enhanced interconnect resources for improved routability
 - Programmable output slew–rate control
- Software design support and automatic place—and—route provided by Altera's development systems for Windows—based PCs and Sun SPARCstations, and HP 9000 Series 700/800 workstations
- Additional design entry and simulation support provided by EDIF 2 0 0 and 3 0 0 netlist files, library of parameterized modules (LPM), Verilog HDL, VHDL, and other interfaces to popular EDA tools from third–party manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplicity, and VeriBest
- Programming support with the Altera master programming unit (MPU), MasterBlasterTM communications cable, ByteBlasterMVTM parallel port download cable, BitBlasterTM serial download cable as well as programming hardware from third–party manufacturers and any in–circuit tester that supports JamTM Standard Test and Programming Language (STAPL) Files (.jam), Jam STAPL Byte-Code Files (.jbc), or Serial Vector Format Files (.svf)

General Description

MAX 3000A devices are low–cost, high–performance devices based on the Altera MAX architecture. Fabricated with advanced CMOS technology, the EEPROM–based MAX 3000A devices operate with a 3.3-V supply voltage and provide 600 to 10,000 usable gates, ISP, pin-to-pin delays as fast as 4.5 ns, and counter speeds of up to 227.3 MHz. MAX 3000A devices in the -4, -5, -6, -7, and -10 speed grades are compatible with the timing requirements of the PCI Special Interest Group (PCI SIG) *PCI Local Bus Specification, Revision 2.2.* See Table 2.

Table 2. MAX	Table 2. MAX 3000A Speed Grades								
Device			Speed Grade	1					
	-4	-5	-6	-7	-10				
EPM3032A	✓			✓	✓				
EPM3064A	✓			✓	✓				
EPM3128A		✓		✓	✓				
EPM3256A				✓	✓				
EPM3512A				✓	✓				

The MAX 3000A architecture supports 100% transistor-to-transistor logic (TTL) emulation and high–density small-scale integration (SSI), medium-scale integration (MSI), and large-scale integration (LSI) logic functions. The MAX 3000A architecture easily integrates multiple devices ranging from PALs, GALs, and 22V10s to MACH and pLSI devices. MAX 3000A devices are available in a wide range of packages, including PLCC, PQFP, and TQFP packages. See Table 3.

Table 3. MAX	3000A Max	Note (1))			
Device	44-Pin PLCC	44-Pin TQFP	100-Pin TQFP	144-Pin TQFP	208-Pin PQFP	256-Pin FineLine BGA
EPM3032A	34	34				
EPM3064A	34	34	66			
EPM3128A			80	96		98
EPM3256A				116	158	161
EPM3512A					172	208

Note:

(1) When the IEEE Std. 1149.1 (JTAG) interface is used for in–system programming or boundary–scan testing, four I/O pins become JTAG pins.

MAX 3000A devices use CMOS EEPROM cells to implement logic functions. The user–configurable MAX 3000A architecture accommodates a variety of independent combinatorial and sequential logic functions. The devices can be reprogrammed for quick and efficient iterations during design development and debugging cycles, and can be programmed and erased up to 100 times.

MAX 3000A devices contain 32 to 512 macrocells, combined into groups of 16 macrocells called logic array blocks (LABs). Each macrocell has a programmable—AND/fixed—OR array and a configurable register with independently programmable clock, clock enable, clear, and preset functions. To build complex logic functions, each macrocell can be supplemented with shareable expander and high—speed parallel expander product terms to provide up to 32 product terms per macrocell.

MAX 3000A devices provide programmable speed/power optimization. Speed-critical portions of a design can run at high speed/full power, while the remaining portions run at reduced speed/low power. This speed/power optimization feature enables the designer to configure one or more macrocells to operate at 50% or lower power while adding only a nominal timing delay. MAX 3000A devices also provide an option that reduces the slew rate of the output buffers, minimizing noise transients when non-speed-critical signals are switching. The output drivers of all MAX 3000A devices can be set for 2.5 V or 3.3 V, and all input pins are 2.5–V, 3.3–V, and 5.0-V tolerant, allowing MAX 3000A devices to be used in mixed-voltage systems.

MAX 3000A devices are supported by Altera development systems, which are integrated packages that offer schematic, text—including VHDL, Verilog HDL, and the Altera Hardware Description Language (AHDL)—and waveform design entry, compilation and logic synthesis, simulation and timing analysis, and device programming. The software provides EDIF 2 0 0 and 3 0 0, LPM, VHDL, Verilog HDL, and other interfaces for additional design entry and simulation support from other industry–standard PC– and UNIX–workstation–based EDA tools. The software runs on Windows–based PCs, as well as Sun SPARCstation, and HP 9000 Series 700/800 workstations.



For more information on development tools, see the MAX+PLUS II Programmable Logic Development System & Software Data Sheet and the Quartus Programmable Logic Development System & Software Data Sheet.

Functional Description

The MAX 3000A architecture includes the following elements:

- Logic array blocks (LABs)
- Macrocells
- Expander product terms (shareable and parallel)
- Programmable interconnect array (PIA)
- I/O control blocks

The MAX 3000A architecture includes four dedicated inputs that can be used as general–purpose inputs or as high–speed, global control signals (clock, clear, and two output enable signals) for each macrocell and I/O pin. Figure 1 shows the architecture of MAX 3000A devices.

For registered functions, each macrocell flipflop can be individually programmed to implement D, T, JK, or SR operation with programmable clock control. The flipflop can be bypassed for combinatorial operation. During design entry, the designer specifies the desired flipflop type; the Altera development system software then selects the most efficient flipflop operation for each registered function to optimize resource utilization.

Each programmable register can be clocked in three different modes:

- Global clock signal mode, which achieves the fastest clock–to–output performance.
- Global clock signal enabled by an active—high clock enable. A clock enable is generated by a product term. This mode provides an enable on each flipflop while still achieving the fast clock—to—output performance of the global clock.
- Array clock implemented with a product term. In this mode, the flipflop can be clocked by signals from buried macrocells or I/O pins.

Two global clock signals are available in MAX 3000A devices. As shown in Figure 1, these global clock signals can be the true or the complement of either of the two global clock pins, GCLK1 or GCLK2.

Each register also supports asynchronous preset and clear functions. As shown in Figure 2, the product–term select matrix allocates product terms to control these operations. Although the product–term–driven preset and clear from the register are active high, active–low control can be obtained by inverting the signal within the logic array. In addition, each register clear function can be individually driven by the active–low dedicated global clear pin (GCLRn).

All registers are cleared upon power-up. By default, all registered outputs drive low when the device is powered up. You can set the registered outputs to drive high upon power-up through the Quartus[®] II software. Quartus II software uses the NOT Gate Push-Back method, which uses an additional macrocell to set the output high. To set this in the Quartus II software, go to the Assignment Editor and set the **Power-Up Level** assignment for the register to **High**.

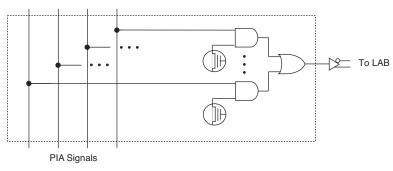
Parallel Expanders

Parallel expanders are unused product terms that can be allocated to a neighboring macrocell to implement fast, complex logic functions. Parallel expanders allow up to 20 product terms to directly feed the macrocell OR logic, with five product terms provided by the macrocell and 15 parallel expanders provided by neighboring macrocells in the LAB.

The Altera development system compiler can automatically allocate up to three sets of up to five parallel expanders to the macrocells that require additional product terms. Each set of five parallel expanders incurs a small, incremental timing delay (t_{PEXP}). For example, if a macrocell requires 14 product terms, the compiler uses the five dedicated product terms within the macrocell and allocates two sets of parallel expanders; the first set includes five product terms, and the second set includes four product terms, increasing the total delay by $2 \times t_{PEXP}$.

Two groups of eight macrocells within each LAB (e.g., macrocells 1 through 8 and 9 through 16) form two chains to lend or borrow parallel expanders. A macrocell borrows parallel expanders from lower–numbered macrocells. For example, macrocell 8 can borrow parallel expanders from macrocell 7, from macrocells 7 and 6, or from macrocells 7, 6, and 5. Within each group of eight, the lowest–numbered macrocell can only lend parallel expanders and the highest–numbered macrocell can only borrow them. Figure 4 shows how parallel expanders can be borrowed from a neighboring macrocell.

Figure 5. MAX 3000A PIA Routing



While the routing delays of channel–based routing schemes in masked or FPGAs are cumulative, variable, and path–dependent, the MAX 3000A PIA has a predictable delay. The PIA makes a design's timing performance easy to predict.

I/O Control Blocks

The I/O control block allows each I/O pin to be individually configured for input, output, or bidirectional operation. All I/O pins have a tri–state buffer that is individually controlled by one of the global output enable signals or directly connected to ground or $V_{CC}.$ Figure 6 shows the I/O control block for MAX 3000A devices. The I/O control block has 6 or 10 global output enable signals that are driven by the true or complement of two output enable signals, a subset of the I/O pins, or a subset of the I/O macrocells.

The instruction register length of MAX 3000A devices is 10 bits. The IDCODE and USERCODE register length is 32 bits. Tables 8 and 9 show the boundary–scan register length and device IDCODE information for MAX 3000A devices.

Table 8. MAX 3000A Boundary-Sc	an Register Length
Device	Boundary–Scan Register Length
EPM3032A	96
EPM3064A	192
EPM3128A	288
EPM3256A	480
EPM3512A	624

Table 9. 32-	Table 9. 32-Bit MAX 3000A Device IDCODE Value Note (1)									
Device		IDCODE (32 I	oits)							
	Version (4 Bits)	Part Number (16 Bits)	Manufacturer's Identity (11 Bits)	1 (1 Bit) (2)						
EPM3032A	0001	0111 0000 0011 0010	00001101110	1						
EPM3064A	0001	0111 0000 0110 0100	00001101110	1						
EPM3128A	0001	0111 0001 0010 1000	00001101110	1						
EPM3256A	0001	0111 0010 0101 0110	00001101110	1						
EPM3512A	0001	0111 0101 0001 0010	00001101110	1						

Notes:

- (1) The most significant bit (MSB) is on the left.
- (2) The least significant bit (LSB) for all JTAG IDCODEs is 1.



See Application Note 39 (IEEE 1149.1 (JTAG) Boundary–Scan Testing in Altera Devices) for more information on JTAG BST.

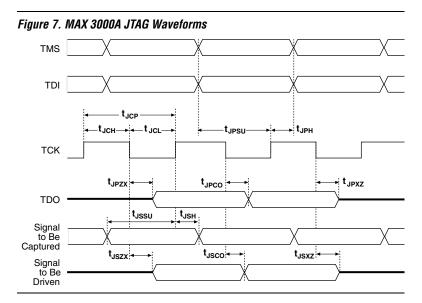


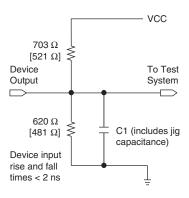
Figure 7 shows the timing information for the JTAG signals.

Table 10 shows the JTAG timing parameters and values for MAX 3000A devices.

Symbol	Parameter	Min	Max	Unit
t _{JCP}	TCK clock period	100		ns
t _{JCH}	TCK clock high time	50		ns
t _{JCL}	TCK clock low time	50		ns
t _{JPSU}	JTAG port setup time	20		ns
t _{JPH}	JTAG port hold time	45		ns
t _{JPCO}	JTAG port clock to output		25	ns
t _{JPZX}	JTAG port high impedance to valid output		25	ns
t _{JPXZ}	JTAG port valid output to high impedance		25	ns
t _{JSSU}	Capture register setup time	20		ns
t _{JSH}	Capture register hold time	45		ns
t _{JSCO}	Update register clock to output		25	ns
t _{JSZX}	Update register high impedance to valid output		25	ns
t _{JSXZ}	Update register valid output to high impedance		25	ns

Figure 8. MAX 3000A AC Test Conditions

Power supply transients can affect AC measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under AC conditions. Large-amplitude, fastground-current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, significant reductions in observable noise immunity can result. Numbers in brackets are for 2.5-V outputs. Numbers without brackets are for 3.3-V devices or outputs.



Operating Conditions

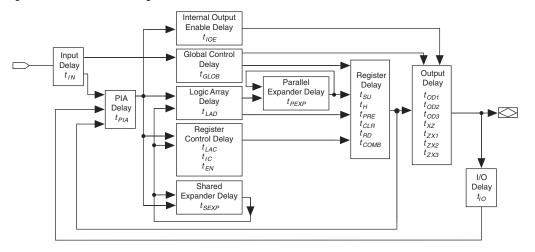
Tables 12 through 15 provide information on absolute maximum ratings, recommended operating conditions, DC operating conditions, and capacitance for MAX 3000A devices.

Table 1	Table 12. MAX 3000A Device Absolute Maximum Ratings Note (1)									
Symbol	Parameter	Conditions	Min	Max	Unit					
V _{CC}	Supply voltage	With respect to ground (2)	-0.5	4.6	V					
VI	DC input voltage		-2.0	5.75	V					
I _{OUT}	DC output current, per pin		-25	25	mA					
T _{STG}	Storage temperature	No bias	-65	150	° C					
T _A	Ambient temperature	Under bias	-65	135	° C					
T_{J}	Junction temperature	PQFP and TQFP packages, under bias		135	° C					

Timing Model

MAX 3000A device timing can be analyzed with the Altera software, with a variety of popular industry–standard EDA simulators and timing analyzers, or with the timing model shown in Figure 10. MAX 3000A devices have predictable internal delays that enable the designer to determine the worst–case timing of any design. The software provides timing simulation, point–to–point delay prediction, and detailed timing analysis for device–wide performance evaluation.

Figure 10. MAX 3000A Timing Model



The timing characteristics of any signal path can be derived from the timing model and parameters of a particular device. External timing parameters, which represent pin–to–pin timing delays, can be calculated as the sum of internal parameters. Figure 11 shows the timing relationship between internal and external delay parameters.

Tables 16 through 23 show EPM3032A, EPM3064A, EPM3128A, EPM3256A, and EPM3512A timing information.

	6. EPM3032A External 1	<u> </u>		Note (1)		•			T
Symbol	Parameter	Conditions			Speed	Grade	1		Unit
			_	4	-7		-10		
			Min	Max	Min	Max	Min	Max	
t _{PD1}	Input to non- registered output	C1 = 35 pF (2)		4.5		7.5		10	ns
t _{PD2}	I/O input to non– registered output	C1 = 35 pF (2)		4.5		7.5		10	ns
t _{SU}	Global clock setup time	(2)	2.9		4.7		6.3		ns
t _H	Global clock hold time	(2)	0.0		0.0		0.0		ns
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.0	1.0	5.0	1.0	6.7	ns
t _{CH}	Global clock high time		2.0		3.0		4.0		ns
t _{CL}	Global clock low time		2.0		3.0		4.0		ns
t _{ASU}	Array clock setup time	(2)	1.6		2.5		3.6		ns
t _{AH}	Array clock hold time	(2)	0.3		0.5		0.5		ns
t _{ACO1}	Array clock to output delay	C1 = 35 pF (2)	1.0	4.3	1.0	7.2	1.0	9.4	ns
t _{ACH}	Array clock high time		2.0		3.0		4.0		ns
t _{ACL}	Array clock low time		2.0		3.0		4.0		ns
t _{CPPW}	Minimum pulse width for clear and preset	(3)	2.0		3.0		4.0		ns
t _{CNT}	Minimum global clock period	(2)		4.4		7.2		9.7	ns
f _{CNT}	Maximum internal global clock frequency	(2), (4)	227.3		138.9		103.1		MHz
t _{ACNT}	Minimum array clock period	(2)		4.4		7.2		9.7	ns
f _{ACNT}	Maximum internal array clock frequency	(2), (4)	227.3		138.9		103.1		MHz

Symbol	Parameter	Conditions			Speed	Grade			Unit
			_	4	_	-7	_	10	
			Min	Max	Min	Max	Min	Max	
t _{IN}	Input pad and buffer delay			0.7		1.2		1.5	ns
t _{IO}	I/O input pad and buffer delay			0.7		1.2		1.5	ns
t _{SEXP}	Shared expander delay			1.9		3.1		4.0	ns
t _{PEXP}	Parallel expander delay			0.5		0.8		1.0	ns
t_{LAD}	Logic array delay			1.5		2.5		3.3	ns
t _{LAC}	Logic control array delay			0.6		1.0		1.2	ns
t _{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t _{OD1}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 3.3 V	C1 = 35 pF		0.8		1.3		1.8	ns
t _{OD2}	Output buffer and pad delay, slow slew rate = off $V_{CCIO} = 2.5 \text{ V}$	C1 = 35 pF		1.3		1.8		2.3	ns
t _{OD3}	Output buffer and pad delay, slow slew rate = on $V_{CCIO} = 2.5 \text{ V or } 3.3 \text{ V}$	C1 = 35 pF		5.8		6.3		6.8	ns
t _{ZX1}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		4.0		4.0		5.0	ns
t _{ZX2}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 2.5 \text{ V}$	C1 = 35 pF		4.5		4.5		5.5	ns
t _{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t _{SU}	Register setup time		1.3		2.0		2.8		ns
t _H	Register hold time		0.6		1.0		1.3		ns
t_{RD}	Register delay			0.7		1.2		1.5	ns
t _{COMB}	Combinatorial delay			0.6		1.0		1.3	ns
t _{IC}	Array clock delay			1.2		2.0		2.5	ns
t _{EN}	Register enable time			0.6		1.0		1.2	ns
t _{GLOB}	Global control delay			0.8		1.3		1.9	ns
t _{PRE}	Register preset time			1.2		1.9		2.6	ns
t _{CLR}	Register clear time			1.2		1.9		2.6	ns

Symbol	Parameter	Conditions			Speed	Grade			Unit
			_	4	_	-7		10	
			Min	Max	Min	Max	Min	Max	
t _{IN}	Input pad and buffer delay			0.6		1.1		1.4	ns
t _{IO}	I/O input pad and buffer delay			0.6		1.1		1.4	ns
t _{SEXP}	Shared expander delay			1.8		3.0		3.9	ns
t _{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.5		2.5		3.2	ns
t_{LAC}	Logic control array delay			0.6		1.0		1.2	ns
t _{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t _{OD1}	Output buffer and pad delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		0.8		1.3		1.8	ns
t _{OD2}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.8		2.3	ns
t _{OD3}	Output buffer and pad delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.3		6.8	ns
t _{ZX1}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		4.0		4.0		5.0	ns
t _{ZX2}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 2.5 \text{ V}$	C1 = 35 pF		4.5		4.5		5.5	ns
t _{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns
t_{SU}	Register setup time		1.3		2.0		2.9		ns
t _H	Register hold time		0.6		1.0		1.3		ns
t _{RD}	Register delay			0.7		1.2		1.6	ns
t _{COMB}	Combinatorial delay			0.6		0.9		1.3	ns
t _{IC}	Array clock delay			1.2		1.9		2.5	ns
t _{EN}	Register enable time			0.6		1.0		1.2	ns
t _{GLOB}	Global control delay			1.0		1.5		2.2	ns
t _{PRE}	Register preset time			1.3		2.1		2.9	ns

Table 19	Table 19. EPM3064A Internal Timing Parameters (Part 2 of 2) Note (1)								
Symbol	Parameter	Conditions			Speed	Grade			Unit
			_	-4		-7		-10	
			Min	Max	Min	Max	Min	Max	
t _{CLR}	Register clear time			1.3		2.1		2.9	ns
t_{PIA}	PIA delay	(2)		1.0		1.7		2.3	ns
t_{LPA}	Low-power adder	(5)		3.5		4.0		5.0	ns

Table 2	D. EPM3128A External 1	iming Param	eters	Note (1)					
Symbol	Parameter	Conditions			Speed	Grade			Unit
			-	5	_	7		10	
			Min	Max	Min	Max	Min	Max	
t _{PD1}	Input to non– registered output	C1 = 35 pF (2)		5.0		7.5		10	ns
t _{PD2}	I/O input to non– registered output	C1 = 35 pF (2)		5.0		7.5		10	ns
t _{SU}	Global clock setup time	(2)	3.3		4.9		6.6		ns
t _H	Global clock hold time	(2)	0.0		0.0		0.0		ns
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.4	1.0	5.0	1.0	6.6	ns
t _{CH}	Global clock high time		2.0		3.0		4.0		ns
t _{CL}	Global clock low time		2.0		3.0		4.0		ns
t _{ASU}	Array clock setup time	(2)	1.8		2.8		3.8		ns
t _{AH}	Array clock hold time	(2)	0.2		0.3		0.4		ns
t _{ACO1}	Array clock to output delay	C1 = 35 pF (2)	1.0	4.9	1.0	7.1	1.0	9.4	ns
t _{ACH}	Array clock high time		2.0		3.0		4.0		ns
t _{ACL}	Array clock low time		2.0		3.0		4.0		ns
t _{CPPW}	Minimum pulse width for clear and preset	(3)	2.0		3.0		4.0		ns
t _{CNT}	Minimum global clock period	(2)		5.2		7.7		10.2	ns
f _{CNT}	Maximum internal global clock frequency	(2), (4)	192.3		129.9		98.0		MHz
t _{ACNT}	Minimum array clock period	(2)		5.2		7.7		10.2	ns

Table 21. EPM3128A Internal Timing Parameters (Part 2 of 2) Note (1)									
Symbol	Parameter	Conditions	Speed Grade						Unit
			-5 -7		-7	-10			
			Min	Max	Min	Max	Min	Max	
t _{SU}	Register setup time		1.4		2.1		2.9		ns
t _H	Register hold time		0.6		1.0		1.3		ns
t _{RD}	Register delay			0.8		1.2		1.6	ns
t _{COMB}	Combinatorial delay			0.5		0.9		1.3	ns
t _{IC}	Array clock delay			1.2		1.7		2.2	ns
t _{EN}	Register enable time			0.7		1.0		1.3	ns
t _{GLOB}	Global control delay			1.1		1.6		2.0	ns
t _{PRE}	Register preset time			1.4		2.0		2.7	ns
t _{CLR}	Register clear time			1.4		2.0		2.7	ns
t _{PIA}	PIA delay	(2)		1.4		2.0		2.6	ns
t _{LPA}	Low-power adder	(5)		4.0		4.0		5.0	ns

Table 22. EPM3256A External Timing Parameters Note (1)									
Symbol	Parameter	Conditions		Unit					
			-7		-10]		
			Min	Max	Min	Max			
t _{PD1}	Input to non–registered output	C1 = 35 pF (2)		7.5		10	ns		
t _{PD2}	I/O input to non–registered output	C1 = 35 pF (2)		7.5		10	ns		
t _{SU}	Global clock setup time	(2)	5.2		6.9		ns		
t _H	Global clock hold time	(2)	0.0		0.0		ns		
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.8	1.0	6.4	ns		
t _{CH}	Global clock high time		3.0		4.0		ns		
t _{CL}	Global clock low time		3.0		4.0		ns		
t _{ASU}	Array clock setup time	(2)	2.7		3.6		ns		
t _{AH}	Array clock hold time	(2)	0.3		0.5		ns		
t _{ACO1}	Array clock to output delay	C1 = 35 pF (2)	1.0	7.3	1.0	9.7	ns		
t _{ACH}	Array clock high time		3.0		4.0		ns		
t _{ACL}	Array clock low time		3.0		4.0		ns		
t _{CPPW}	Minimum pulse width for clear and preset	(3)	3.0		4.0		ns		

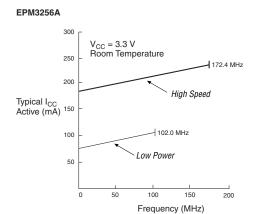
Symbol	Parameter	Conditions		Speed	Grade		Unit
			_	7	-10		1
			Min	Max	Min	Max]
t _{CNT}	Minimum global clock period	(2)		7.9		10.5	ns
f _{CNT}	Maximum internal global clock frequency	(2), (4)	126.6		95.2		MHz
t _{ACNT}	Minimum array clock period	(2)		7.9		10.5	ns
f _{ACNT}	Maximum internal array clock frequency	(2), (4)	126.6		95.2		MHz

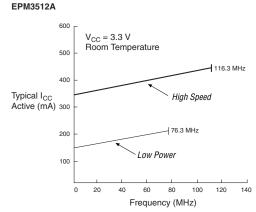
Symbol	Parameter	Conditions		Speed Grade				
			-	-7	-10			
			Min	Max	Min	Max		
t _{IN}	Input pad and buffer delay			0.9		1.2	ns	
t _{IO}	I/O input pad and buffer delay			0.9		1.2	ns	
t _{SEXP}	Shared expander delay			2.8		3.7	ns	
t _{PEXP}	Parallel expander delay			0.5		0.6	ns	
t_{LAD}	Logic array delay			2.2		2.8	ns	
t_{LAC}	Logic control array delay			1.0		1.3	ns	
t _{IOE}	Internal output enable delay			0.0		0.0	ns	
t _{OD1}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 3.3 V	C1 = 35 pF		1.2		1.6	ns	
t _{OD2}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		1.7		2.1	ns	
t _{OD3}	Output buffer and pad delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		6.2		6.6	ns	
t _{ZX1}	Output buffer enable delay, slow slew rate = off V _{CCIO} = 3.3 V	C1 = 35 pF		4.0		5.0	ns	
t _{ZX2}	Output buffer enable delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		4.5		5.5	ns	

Table 23. EPM3256A Internal Timing Parameters (Part 2 of 2) Note (1)								
Symbol	Parameter	Conditions		Speed	Unit			
			-7			-10		
			Min	Max	Min	Max		
t_{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		10.0	ns	
t _{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		5.0	ns	
t _{SU}	Register setup time		2.1		2.9		ns	
t_H	Register hold time		0.9		1.2		ns	
t _{RD}	Register delay			1.2		1.6	ns	
t _{COMB}	Combinatorial delay			0.8		1.2	ns	
t _{IC}	Array clock delay			1.6		2.1	ns	
t _{EN}	Register enable time			1.0		1.3	ns	
t _{GLOB}	Global control delay			1.5		2.0	ns	
t _{PRE}	Register preset time			2.3		3.0	ns	
t _{CLR}	Register clear time			2.3		3.0	ns	
t_{PIA}	PIA delay	(2)		2.4		3.2	ns	
t_{LPA}	Low-power adder	(5)		4.0		5.0	ns	

Table 24. EPM3512A External Timing Parameters Note (1)									
Symbol	Parameter	Conditions		Unit					
			-7		-10				
			Min	Max	Min	Max			
t _{PD1}	Input to non-registered output	C1 = 35 pF (2)		7.5		10.0	ns		
t _{PD2}	I/O input to non-registered output	C1 = 35 pF (2)		7.5		10.0	ns		
t _{SU}	Global clock setup time	(2)	5.6		7.6		ns		
t _H	Global clock hold time	(2)	0.0		0.0		ns		
t _{FSU}	Global clock setup time of fast input		3.0		3.0		ns		
t _{FH}	Global clock hold time of fast input		0.0		0.0		ns		
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.7	1.0	6.3	ns		
t _{CH}	Global clock high time		3.0		4.0		ns		
t _{CL}	Global clock low time		3.0		4.0		ns		
t _{ASU}	Array clock setup time	(2)	2.5		3.5		ns		

Figure 13. I_{CC} vs. Frequency for MAX 3000A Devices





Device Pin-Outs

See the Altera web site (http://www.altera.com) or the *Altera Digital Library* for pin–out information.

Figures 14 through 18 show the package pin-out diagrams for MAX 3000A devices.

Figure 14. 44-Pin PLCC/TQFP Package Pin-Out Diagram

Package outlines not drawn to scale.

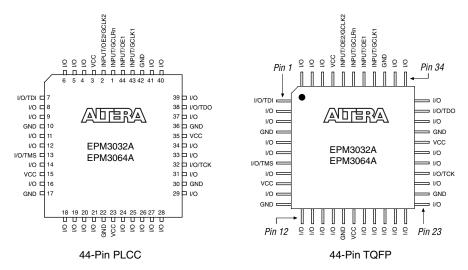
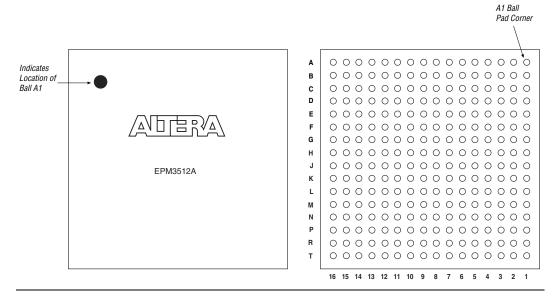


Figure 18. 256-Pin FineLine BGA Package Pin-Out Diagram

Package outline not drawn to scale.



Revision History

The information contained in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.5 supersedes information published in previous versions. The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.5:

Version 3.5

The following changes were made in the MAX 3000A Programmable Logic Device Data Sheet version 3.5:

■ New paragraph added before "Expander Product Terms".

Version 3.4

The following changes were made in the MAX 3000A Programmable Logic Device Data Sheet version 3.4:

■ Updated Table 1.